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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# International **IR** Rectifier

## IRF7524D1PbF

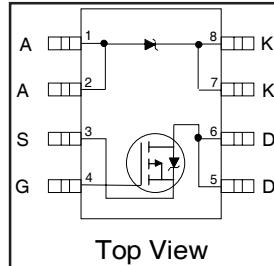
### FETKY™ MOSFET & Schottky Diode

- Co-packaged HEXFET® Power MOSFET and Schottky Diode
- P-Channel HEXFET
- Low  $V_F$  Schottky Rectifier
- Generation 5 Technology
- Micro8™ Footprint
- Lead-Free

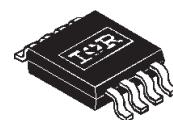
#### Description

The FETKY™ family of co-packaged HEXFETs and Schottky diodes offer the designer an innovative board space saving solution for switching regulator applications. Generation 5 HEXFETs utilize advanced processing techniques to achieve extremely low on-resistance per silicon area. Combining this technology with International Rectifier's low forward drop Schottky rectifiers results in an extremely efficient device suitable for use in a wide variety of portable electronics applications like cell phone, PDA, etc.

The new Micro8™ package, with half the footprint area of the standard SO-8, provides the smallest footprint available in an SOIC outline. This makes the Micro8™ an ideal device for applications where printed circuit board space is at a premium. The low profile (<1.1mm) of the Micro8™ will allow it to fit easily into extremely thin application environments such as portable electronics and PCMCIA cards.



$V_{DSS} = -20V$   
 $R_{DS(on)} = 0.27\Omega$   
 Schottky  $V_f = 0.39V$



Micro8™

#### Absolute Maximum Ratings

Parameter	Maximum	Units
$I_D @ T_A = 25^\circ C$	-1.7	A
$I_D @ T_A = 70^\circ C$	-1.4	
$I_{DM}$	-14	
$P_D @ T_A = 25^\circ C$	1.25	W
$P_D @ T_A = 70^\circ C$	0.8	
$V_{GS}$	10	mW/°C
$dV/dt$	$\pm 12$	V
$T_J, T_{STG}$	Peak Diode Recovery $dV/dt$ ②	V/ns
	Junction and Storage Temperature Range	-55 to +150 °C

#### Thermal Resistance Ratings

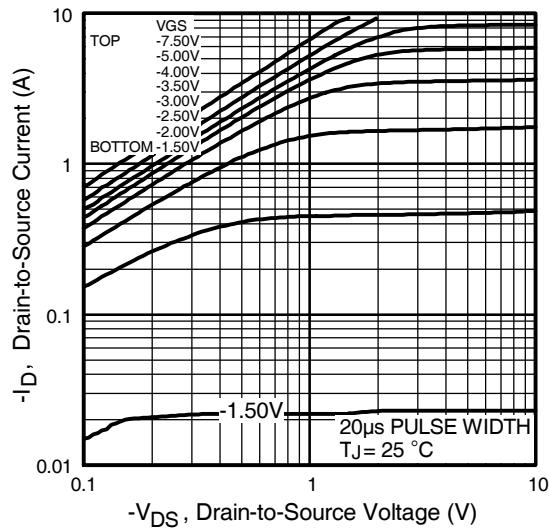
Parameter	Maximum	Units
$R_{θJA}$	100	°C/W

#### Notes:

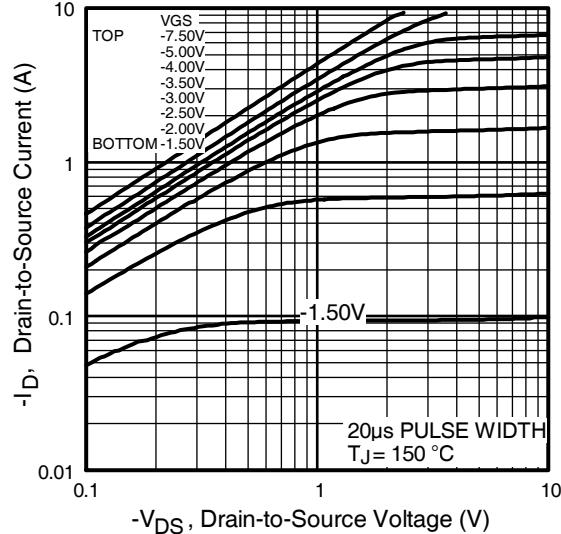
- ① Repetitive rating – pulse width limited by max. junction temperature (see Fig. 9)
- ②  $I_{SD} \leq -1.2A$ ,  $di/dt \leq 100A/\mu s$ ,  $V_{DD} \leq V_{(BR)DSS}$ ,  $T_J \leq 150^\circ C$
- ③ Pulse width  $\leq 300\mu s$  – duty cycle  $\leq 2\%$
- ④ When mounted on 1 inch square copper board to approximate typical multi-layer PCB thermal resistance



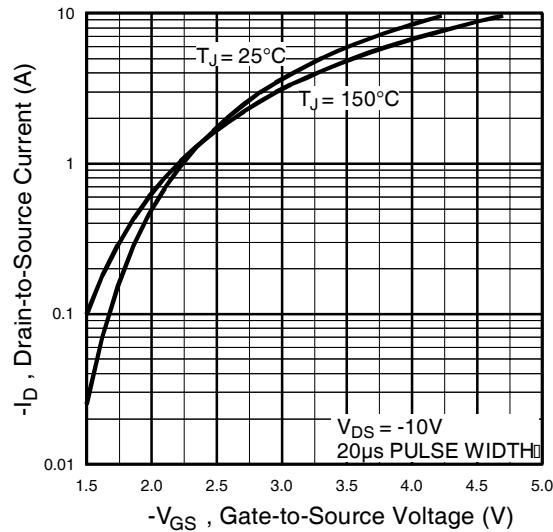
**Power Mosfet Characteristics**



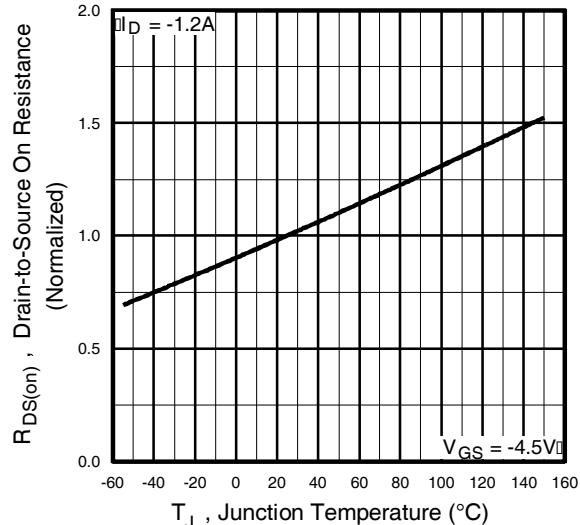
**Fig 1.** Typical Output Characteristics



**Fig 2.** Typical Output Characteristics



**Fig 3.** Typical Transfer Characteristics



**Fig 4.** Normalized On-Resistance  
Vs. Temperature

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Rectifier

## Power Mosfet Characteristics

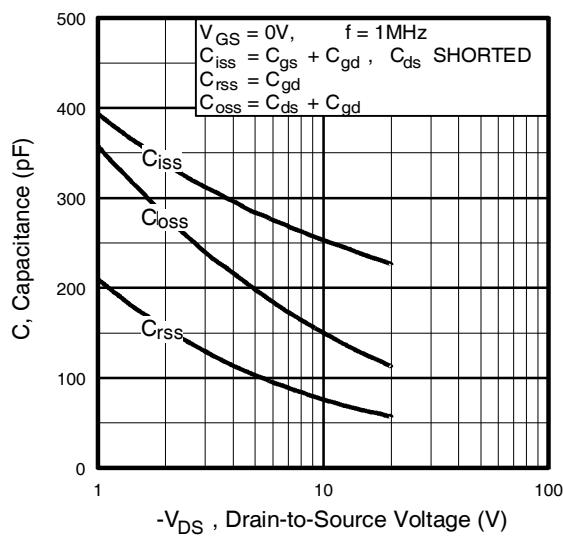


Fig 5. Typical Capacitance Vs.  
Drain-to-Source Voltage

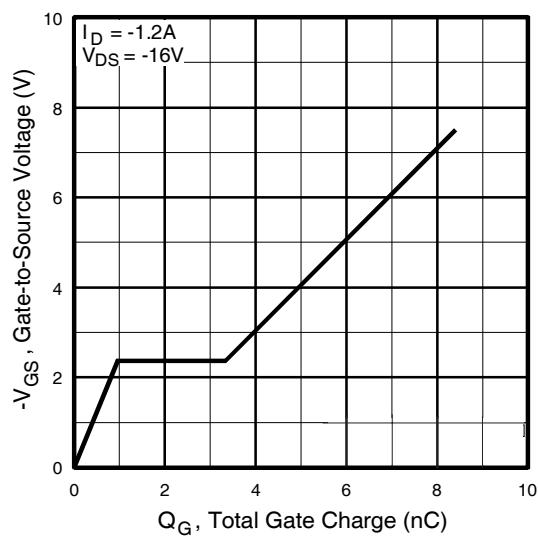


Fig 6. Typical Gate Charge Vs.  
Gate-to-Source Voltage

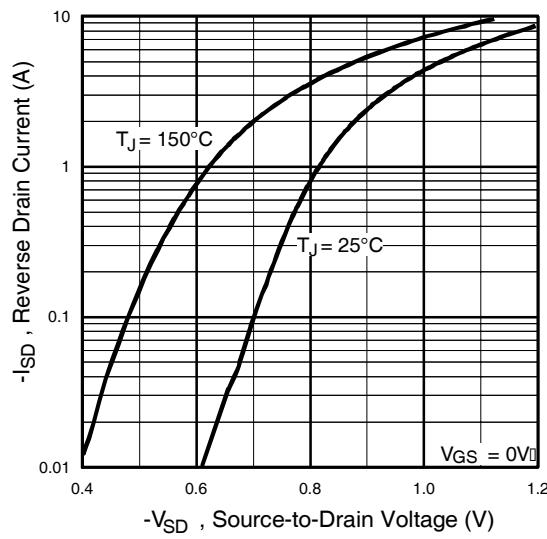


Fig 7. Typical Source-Drain Diode  
Forward Voltage

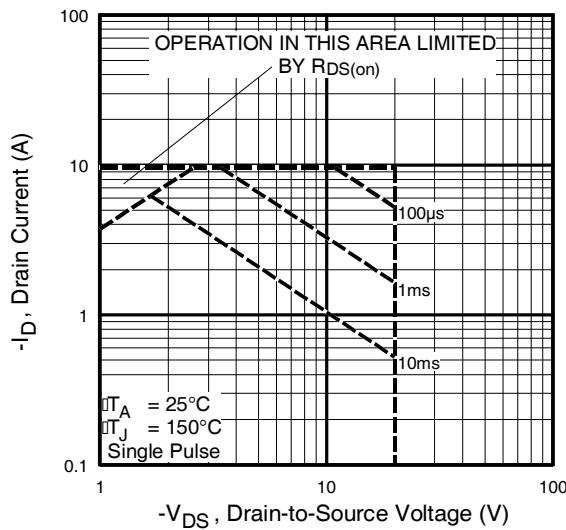
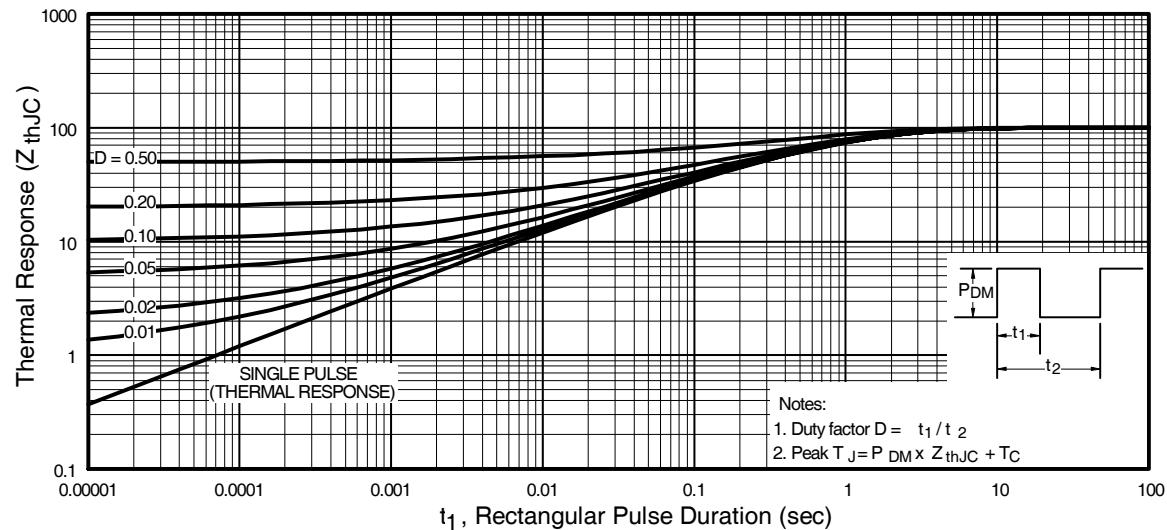
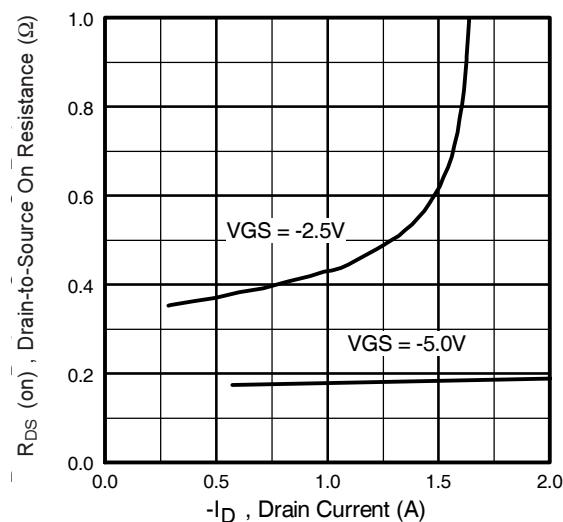


Fig 8. Maximum Safe Operating Area

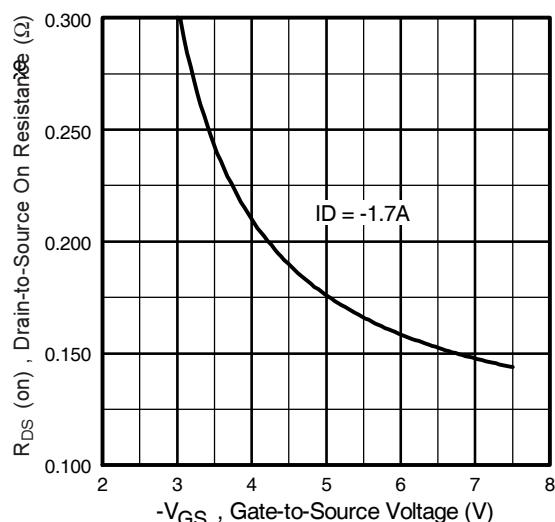
### Power Mosfet Characteristics



**Fig 9.** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



**Fig 10.** Typical On-Resistance Vs. Drain Current

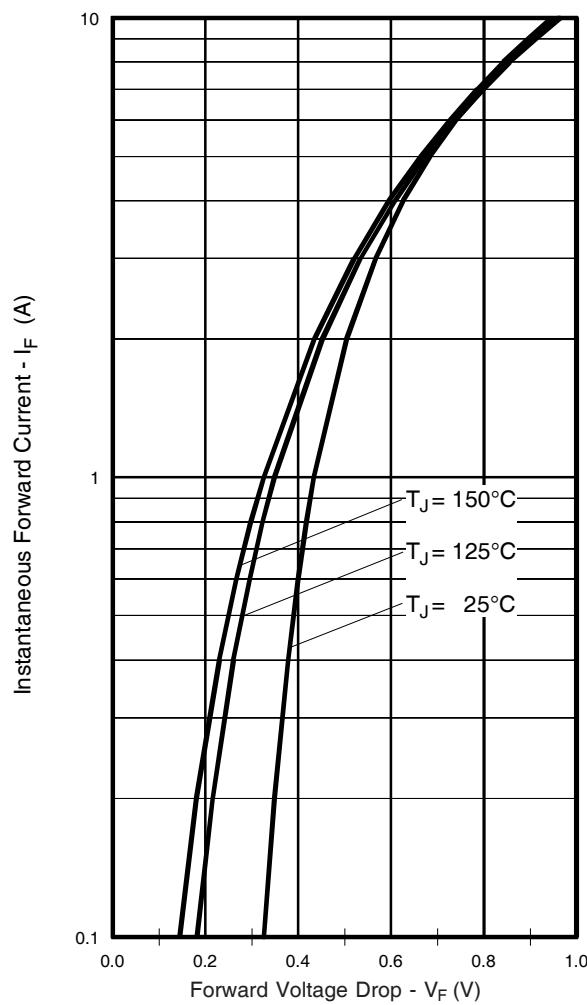


**Fig 11.** Typical On-Resistance Vs. Gate Voltage

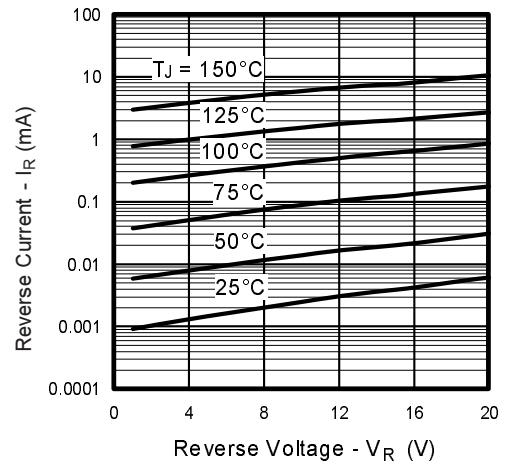
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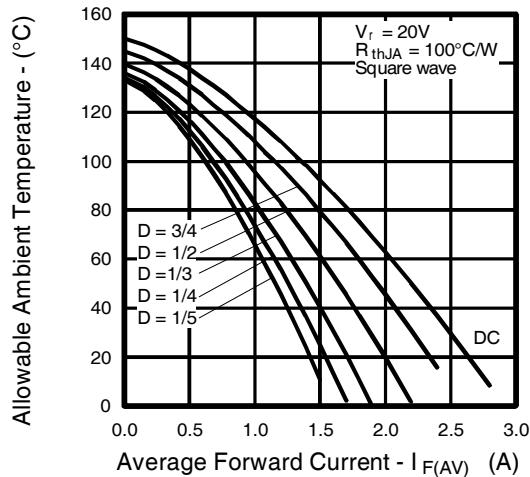
## Schottky Diode Characteristics



**Fig. 12** -Typical Forward Voltage Drop Characteristics



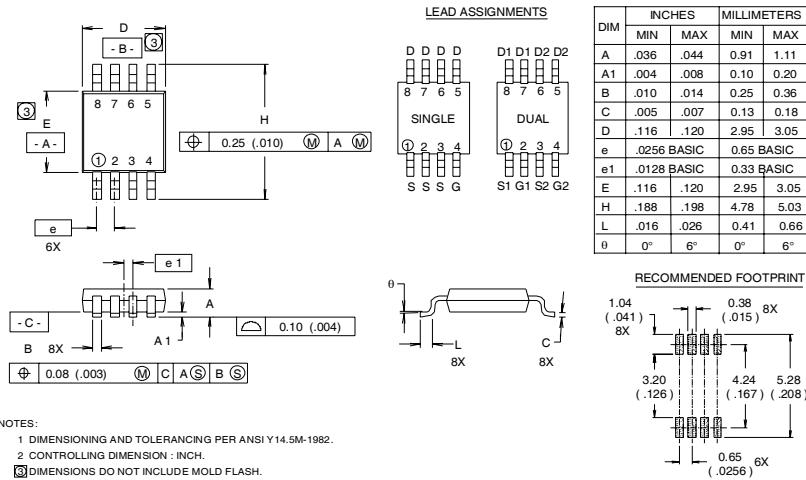
**Fig. 13** - Typical Values of Reverse Current Vs. Reverse Voltage



**Fig.14** - Maximum Allowable Ambient Temp. Vs. Forward Current

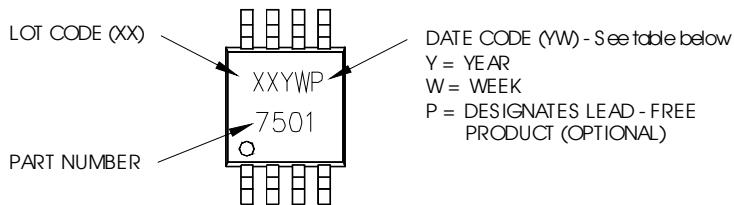
## Micro8 Package Outline

Dimensions are shown in millimeters (inches)



## Micro8 Part Marking Information

EXAMPLE: THIS IS AN IRF7501



WW = (1-26) IF PRECEDED BY LAST DIGIT OF CALENDAR YEAR

YEAR	Y	WORK WEEK	W
2001	1	01	A
2002	2	02	B
2003	3	03	C
2004	4	04	D
2005	5		
2006	6		
2007	7		
2008	8		
2009	9		
2010	0	24	X
		25	Y
		26	Z

WW = (27-52) IF PRECEDED BY A LETTER

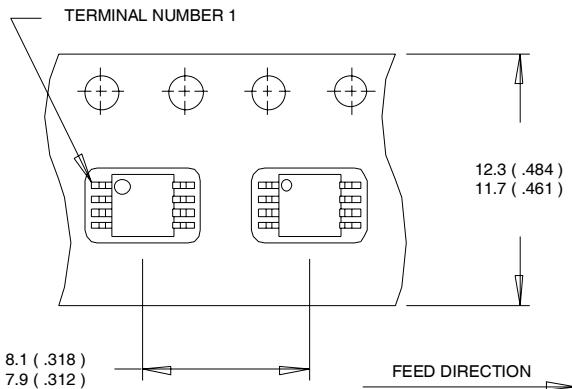
YEAR	Y	WORK WEEK	W
2001	A	27	A
2002	B	28	B
2003	C	29	C
2004	D	30	D
2005	E		
2006	F		
2007	G		
2008	H		
2009	J		
2010	K	50	X
		51	Y
		52	Z

# IRF7524D1PbF

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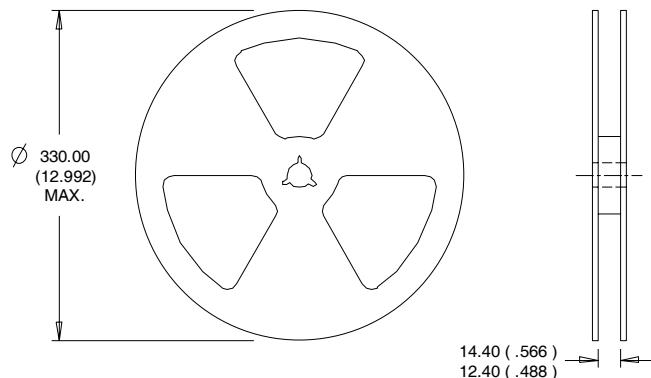
## Micro8 Tape & Reel Information

Dimensions are shown in millimeters (inches)



NOTES:

1. OUTLINE CONFORMS TO EIA-481 & EIA-541.
2. CONTROLLING DIMENSION : MILLIMETER.



NOTES :

1. CONTROLLING DIMENSION : MILLIMETER.
2. OUTLINE CONFORMS TO EIA-481 & EIA-541.

Data and specifications subject to change without notice.  
This product has been designed and qualified for the Consumer market.  
Qualification Standards can be found on IR's Web site.

International  
**IR** Rectifier

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